

April 1995

## 75A, 1200V Ultrafast Diode

### Features

- Ultrafast with Soft Recovery . . . . . <125ns
- Operating Temperature . . . . . +175°C
- Reverse Voltage . . . . . 1200V
- Avalanche Energy Rated
- Planar Construction

### Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

### Description

The RURG75120 (TA49032) is an ultrafast diode with soft recovery characteristics ( $t_{RR} < 125\text{ns}$ ). It has low forward voltage drop and is silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and ultrafast recovery with soft recovery characteristic minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

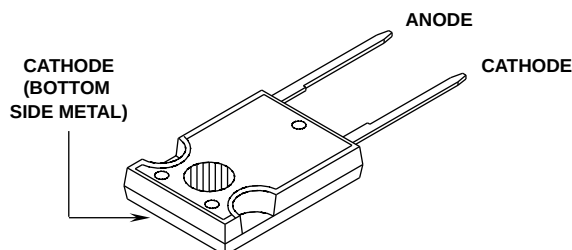
#### PACKAGING AVAILABILITY

| PART NUMBER | PACKAGE | BRAND     |
|-------------|---------|-----------|
| RURG75120   | TO-247  | RURG75120 |

NOTE: When ordering, use the entire part number.

### Package

JEDEC STYLE 2 LEAD TO-247



### Symbol



### Absolute Maximum Ratings $T_C = +25^\circ\text{C}$ , Unless Otherwise Specified

|                                                                                             | RURG75120   | UNITS |
|---------------------------------------------------------------------------------------------|-------------|-------|
| Peak Repetitive Reverse Voltage . . . . . $V_{RRM}$                                         | 1200        | V     |
| Working Peak Reverse Voltage . . . . . $V_{RWM}$                                            | 1200        | V     |
| DC Blocking Voltage. . . . . $V_R$                                                          | 1200        | V     |
| Average Rectified Forward Current . . . . . $I_{F(AV)}$<br>( $T_C = +54.75^\circ\text{C}$ ) | 75          | A     |
| Repetitive Peak Surge Current. . . . . $I_{FSM}$<br>(Square Wave, 20kHz)                    | 150         | A     |
| Nonrepetitive Peak Surge Current . . . . . $I_{FSM}$<br>(Halfwave, 1 Phase, 60Hz)           | 500         | A     |
| Maximum Power Dissipation . . . . . $P_D$                                                   | 190         | W     |
| Avalanche Energy ( $L = 40\text{mH}$ ) . . . . . $E_{AVL}$                                  | 50          | mj    |
| Operating and Storage Temperature . . . . . $T_{STG}, T_J$                                  | -65 to +175 | °C    |

# Specifications RURG75120

## Electrical Specifications $T_C = +25^{\circ}\text{C}$ , Unless Otherwise Specified

| SYMBOL          | TEST CONDITION                                           | LIMITS |     |     | UNITS                       |
|-----------------|----------------------------------------------------------|--------|-----|-----|-----------------------------|
|                 |                                                          | MIN    | TYP | MAX |                             |
| $V_F$           | $I_F = 75\text{A}$                                       | -      | -   | 2.1 | V                           |
| $V_F$           | $I_F = 75\text{A}$ $T_C = +150^{\circ}\text{C}$          | -      | -   | 1.9 | V                           |
| $I_R$           | $V_R = 1200\text{V}$                                     | -      | -   | 500 | $\mu\text{A}$               |
| $I_R$           | $V_R = 1200\text{V}$ $T_C = +150^{\circ}\text{C}$        | -      | -   | 2   | mA                          |
| $t_{RR}$        | $I_F = 1\text{A}$ , $di_F/dt = 100\text{A}/\mu\text{s}$  | -      | -   | 125 | ns                          |
| $t_{RR}$        | $I_F = 75\text{A}$ , $di_F/dt = 100\text{A}/\mu\text{s}$ | -      | -   | 200 | ns                          |
| $t_A$           | $I_F = 75\text{A}$ , $di_F/dt = 100\text{A}/\mu\text{s}$ | -      | 90  | -   | ns                          |
| $t_B$           | $I_F = 75\text{A}$ , $di_F/dt = 100\text{A}/\mu\text{s}$ | -      | 65  | -   | ns                          |
| $R_{\theta JC}$ |                                                          | -      | -   | 0.8 | $^{\circ}\text{C}/\text{W}$ |

### DEFINITIONS

$V_F$  = Instantaneous forward voltage ( $p_w = 300\mu\text{s}$ ,  $D = 2\%$ ).

$I_R$  = Instantaneous reverse current.

$t_{RR}$  = Reverse recovery time (See Figure 2), summation of  $t_A + t_B$ .

$t_A$  = Time to reach peak reverse current (See Figure 2).

$t_B$  = Time from peak  $I_{RM}$  to projected zero crossing of  $I_{RM}$  based on a straight line from peak  $I_{RM}$  through 25% of  $I_{RM}$  (See Figure 2).

$R_{\theta JC}$  = Thermal resistance junction to case.

$E_{AVL}$  = Controlled avalanche energy (See Figures 7 and 8).

$p_w$  = pulse width.

$D$  = duty cycle.

$V_1$  AMPLITUDE CONTROLS  $I_F$   
 $V_2$  AMPLITUDE CONTROLS  $di_F/dt$   
 $L_1$  = SELF INDUCTANCE OF  
 $R_4 + L_{\text{LOOP}}$

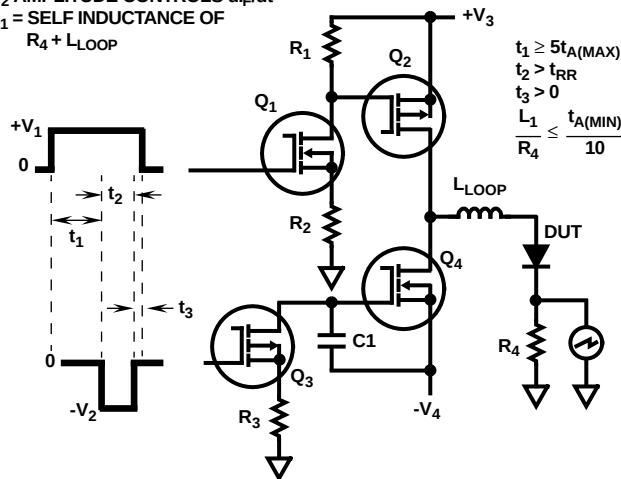


FIGURE 1.  $t_{RR}$  TEST CIRCUIT

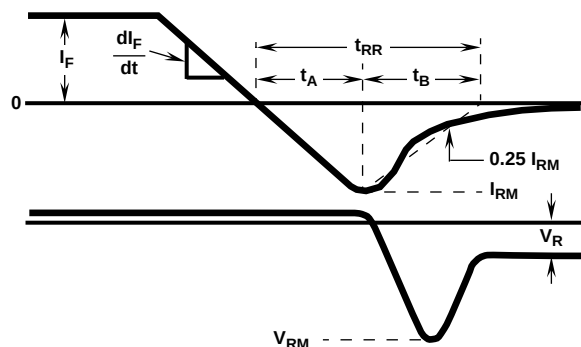


FIGURE 2.  $t_{RR}$  WAVEFORMS AND DEFINITIONS

## Typical Performance Curves

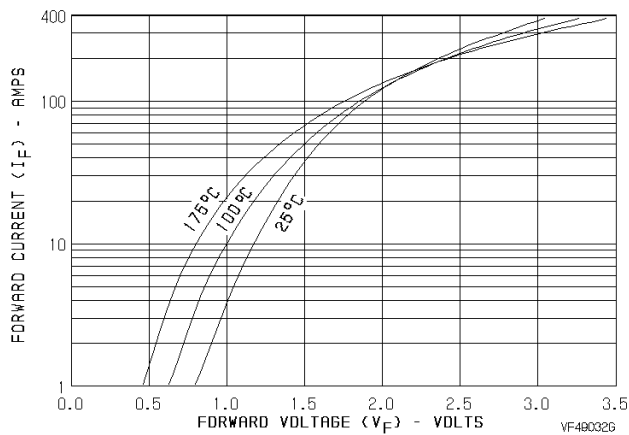


FIGURE 3. TYPICAL FORWARD CURRENT vs FORWARD VOLTAGE DROP

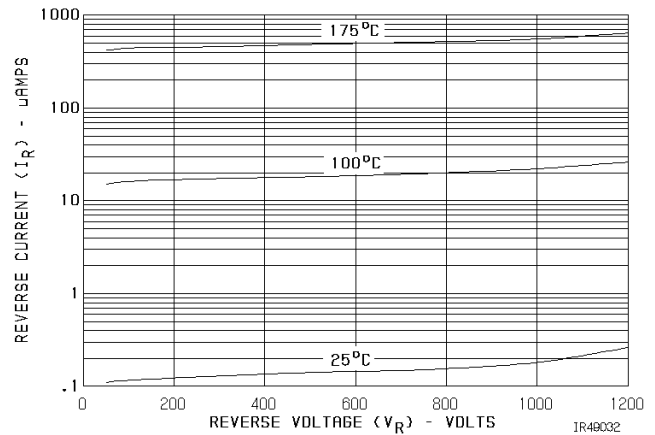


FIGURE 4. TYPICAL REVERSE CURRENT vs VOLTAGE

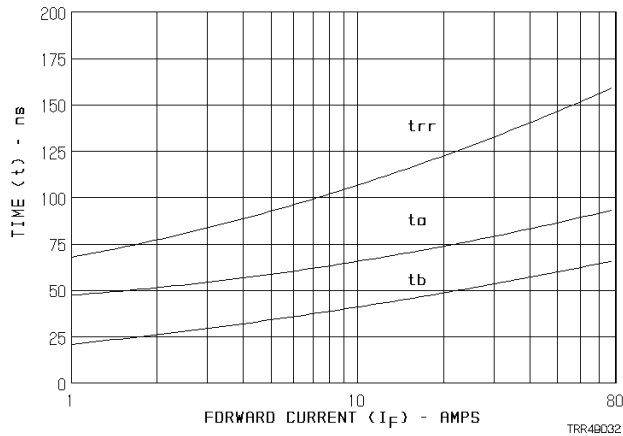


FIGURE 5. TYPICAL  $t_{RR}$ ,  $t_A$  AND  $t_B$  CURVES vs FORWARD CURRENT

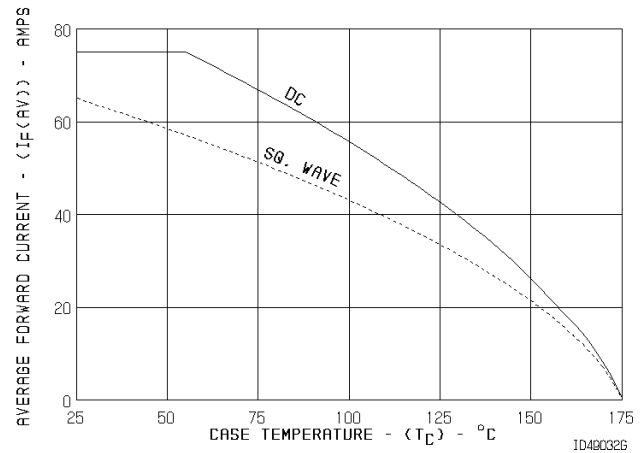


FIGURE 6. CURRENT DERATING CURVE FOR ALL TYPES

$I_{MAX} = 1A$

$L = 40mH$

$R < 0.1\Omega$

$E_{AVL} = 1/2 L I^2 [V_{AVL}/(V_{AVL} - V_{DD})]$

$Q_1$  AND  $Q_2$  ARE 1000V MOSFETS

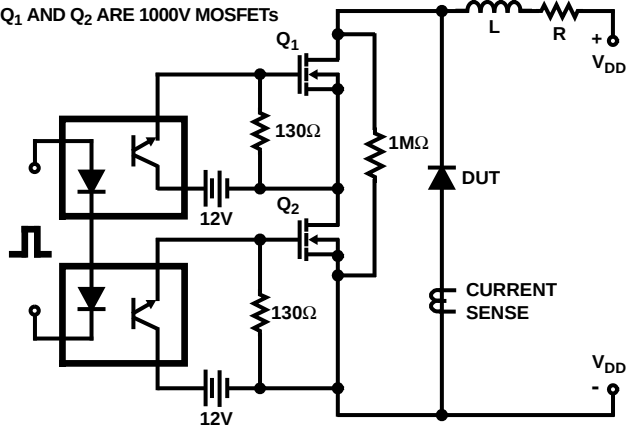


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

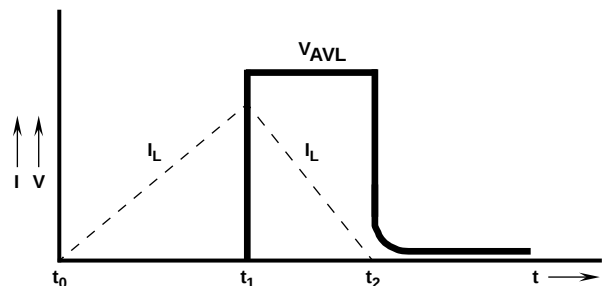


FIGURE 8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS